D issipation e ects in spin-H all transport of electrons and holes

John Schliem ann and Daniel Loss
Department of Physics and Astronomy, University of Basel, CH-4056 Basel, Switzerland
(April 14, 2024)

We investigate the spin-Halle ect of both electrons and holes in semiconductors using the Kubo formula in the correct zero-frequency limit taking into account the nite momentum relaxation time of carriers in real semiconductors. This approach allows to analyze the range of validity of recent theoretical notings. In particular, the spin-Hall conductivity vanishes for vanishing spin-orbit coupling if the correct zero-frequency limit is performed.

I. IN TRODUCTION

In the recent years, an increasing interest in spindependent phenom ena in sem iconductors has developed, mostly in the eld of spin electronics, which has by now become a major branch of solid state research 113. On of the most investigated issues in this eld is the in uence of spin-orbit coupling on various transport properties of both electrons and holes. M any of these studies were inspired by the paradigm atic proposal of a spin elde ect transistor due to D atta and D as⁴; for recent work in this direction see e.g. Refs. 5 {13}. Most recently, interesting theoretical studies on the spin-Halle ect have been perform ed 14 {16. This e ect amounts in a spin current (as opposed to a charge current) driven by an electric eld perpendicular to it. In the present letter we reexam ine these ndings using the Kubo formula with full frequency dependence, treating both the case of electrons¹⁵ and holes 14;16, and analyze the range of validity of previous theoretical results obtained for the case of direct current. Here it is crucial to perform the correct zerofrequency limit taking into account an imaginary part of the frequencies occurring the the K ubo form ula.

The notion of the spin-Halle ect in systems of itinerant spinful carriers was considered rst by Dyakonov and Perel¹⁷ in the early seventies, and, independently, in am ore recent paper by Hirsch¹⁸. In these studies the predicted spin-Halle ect is due to spin-orbite ects in uencing scattering processes upon static im purities. Follow ing the term inology used in 15;16 this is referred to as the extrinsic spin-Halle ect since it depends on impurity scattering. This is in contrast to the intrinsic spin-Halle ect predicted very recently in Refs. 4 16 which is entirely due to spin-orbit coupling terms in the single-particle carrier Ham iltonian and independent of any scattering process. As we shall see below, this distinction between intrinsic and extrinsic e ects becomes ambiguous in the lim it of weak spin-orbit coupling when life timee ects of carrier quasiparticles have to be taken into account.

Yet another type of spin-H all e ect was studied recently by M eier and $Loss^{19}$ in a two-dim ensional H eisenberg m odel consisting of isolated spins, in contrast to the itinerant-carrier system s m entioned before.

Spin-orbit coupling also induces o -diagonal components of the conductivity tensor for charge transport.

An important example is the anomalous Halle ect as it occurs in sem iconductors in the presence of magnetic im purities²⁰. Here, as in the case of the aforem entioned spin-Halle ect, the o -diagonal elements of the charge conductivity tensor are the same in magnitude but dier in sign. Therefore, this antisymm etric conductivity tensorhas the sam e com ponents in allorthogonal coordinate systems, and in this sense the transport properties are isotropic. This is dierent from charge transport of electrons in quantum wells as investigated recently Ref. 12. In such systems, the presence of spin-orbit coupling of both the Rashba²¹ and the D resselhaus²² type leads to anisotropic dispersion relations and Ferm i contours. This feature leads to symmetric o -diagonal elements in the conductivity tensor and therefore to preferred eigendirections for charge transport 12;11. This predicted e ect offers a possibilty to detect spin-orbit coupling by measuring di ussive spin-unpolarized charge currents in a Halltype geometry, which should be a comparatively simple experim ental task.

This paper is organized as follows. In section II we sum marize elementary properties of linear-response theory as given by the Kubo formula. This technique is applied then in section III to spin-Hall transport of electrons in a quantum well in the presence of Rashba spin-orbit coupling. In section IV we investigate the case of bulk holes described by the Luttinger Ham iltonian in the spherical approximation. We end with conclusions in section V.

II.KUBO FORM ULA AND ZERO-FREQUENCY LIM IT

Our present study of spin-Halle ect of electrons and holes in sem iconductors is based on the usual K ubo formula with full frequency dependence for a spatially homogeneous electric eld^{23} ,

where we have assumed zero temperature T = 0 and non-interacting carriers, which allows to formulate the two-

body G reen's function entering the conductivity K ubo form ula in terms of single-particle operators. A is the volume of the system, e is the elementary charge, and f (" (K)) is the T = 0 Ferm i distribution function for energy " (K) at wave vector K in a dispersion branch labeled by . The velocity operators are given by $\mathbf{v} = \mathbf{i} [H \ ; r] = \mathbf{h}$ where r is the position operator, and H is the single-particle H am iltonian not including the external electric eld. The spin-current operator (in the D irac picture) for spin m om ent polarized along the z-direction and owing in the x-direction is given by

$$j_x^{S,z}(t) = e^{iH} t^{-h} \frac{1}{2} (s^z v_x + v_x s^z) e^{iH} t^{-h};$$
 (2)

where s is the spin operator. The right hand side of Eq. (1) has to be understood in the lim it of vanishing im aginary part > 0 in the frequency argument. This im aginary part in the frequency rejects the fact that the external electric eld is assumed to be switched on adiabatically starting from the in nite past of the system, and it also ensures causality properties of the retarded G reen's function occurring in Eq. (1). In general, and as we will discuss in more detail below, the limiting process

! 0 does not com mute with other limits, and, in particular, the dc-limit!! 0 has to be taken with care 23 . In the presence of random impurity scattering, the retarded two-body G reen's function in Eq. (1) will generically have a frequency argument with positive imaginary part 23 . In this case the limit! 0 is unproblematic, and the imaginary part of the frequency argument is just due to impurity scattering and/or other (many-body) elects. Generically, and as we will discuss in more detail below, the imaginary part > 0 corresponds to a nite carrier quasiparticle lifetime.

III. ELECTRONS W ITH RASHBA COUPLING

Sinova et al. have considered the spin-Halle ect of non-interacting electrons con ned to the two-dimensional (xy-) plane of a quantum well and being subject to Rashba spin-orbit coupling $^{21;3}$,

$$H = \frac{p^2}{2m} + \frac{1}{h} (p_x y p_y x);$$
 (3)

where m is the elective mass, the Rashba coelcient, and the other notations are standard. We note that in systems where both the Rashba and the Dresselhaus spinorbit coupling are present, various interesting transport elects can arise from the interplay of these two terms, for recent studies see e.g. $5:7 \cdot \{9:11:12\}$. For simplicity, however, we shall concentrate here on the Rashba term only. The Hamiltonian (3) has two energy branches,

"
$$(K) = \frac{h^2 k^2}{2m}$$
 k (4)

with eigenstates

$$\operatorname{hr}_{K}; \quad i = \frac{e^{iKr}}{P} \frac{1}{A} \qquad \qquad i \qquad \qquad i \qquad \qquad i \qquad \qquad (5)$$

where $(K) = arg(k_y + ik_x)$. By a straightforward calculation one obtains for the spin-Hall conductivity

$$\sum_{xy}^{S;z} (!) = \sum_{yx}^{S;z} (!)
= \frac{e}{4m} \sum_{k_f^+}^{Z} dk \frac{k^2}{(!+i)^2 \frac{2k}{h}^2}; \quad (6)$$

w here

$$k_{f} = \frac{2m}{h^{2}} r_{f} + \frac{m}{h^{2}} r_{f}^{2}$$
 (7)

are the Ferm i m om enta on the two dispersion branches for positive Ferm ienergy " $_{\rm f}$ > 0. In the presence of scattering on static random impurities, the imaginary part

> 0 in the frequency argument is given, to lowest order in the Rashba coe cient and the impurity potential, by the inverse of the momentum relaxation time. This is certainly a very intuitive result; however, let us sketch a formal proof for this assertion. The time-dependent spin-current operator in the presence of Rashba coupling reads

$$j_x^{S} i^z$$
 (t) = $\frac{h}{2m} z$ (t) p_x (t) (8)

where the time evolution includes impurity scattering. To lowest order in the spin-orbit coupling and the impurity scattering we have

$$j_x^{S;z}$$
 (t) $\frac{h}{2m} = \frac{z}{0}$ (t) p_x^0 (t) (9)

where the time evolution of $^{\circ}_{z}$ is only due to the H am iltonian (3) and evaluated in the above expression (6), while p_{x}^{0} (t) contains the impurity scattering but not the spinorbit coupling. Now it is useful to note that, in order to compute the expectation values in the K ubo formula Eq. (1), only matrix elements of the time-dependent momentum operator p_{x}^{0} (t) which are diagonal in the wave vector index are needed. This enables to apply superoperator techniques developed in Refs. 24 yielding

$$p_{x}^{0}$$
 (t) $_{kk}$ e $^{\circ}$ $^{t}p_{x}^{0}$ (0) $_{kk}$ = e $^{t=}$ p_{x}^{0} (0) $_{kk}$; (10)

where $_0$ is the scattering m aster operator in lowest order of the scattering potential 4 . It is the same operator as it occurs as the scattering term in the usual Boltzmann equation when evaluated in lowest oder via Ferm i's golden rule. For in purity potentials being isotropic in real space, the momentum p_x is an exact eigenfunction of $_0$, and the eigenvalue is given by the well-known inverse momentum relaxation time 1= (") $^{24;25}$ which in

general depends on the energy "(K). To lowest order in the Rashba coupling, this energy argument can be replaced with the Fermi energy in the absence of spin-orbit interaction. We note that this momentum relaxation rate 1= is the same as obtained in the standard diagrammatic approach and thus contains the vertex correction 23. However, this vertex correction vanishes for short-range isotropic scatterers. The above argumentation refers to the Rashba Hamiltonian (3) for conduction band electrons; similar considerations can be performed in the case of valence band holes to be discussed further below.

For ! = 0, but nite m om entum relaxation rate 1 = > 0, Eq. (6) yields

where we have introduced the \R ashba energy" "_R = m 2 =h². Clearly, this is the energy which has to be compared with the energy scale h= of the impurity scattering in order to obtain the correct zero-frequency limit of the spin Hall conductivity. If the impurity scattering is weak compared to spin-orbit coupling, "_R =h 1, we have the expansion

$$S_{xy}^{S,z}(0) = \frac{e}{8} \frac{e}{64} \frac{(h=\hat{y}^2)}{\mathbf{n}_R^2 \mathbf{n}_f} + 0 \frac{h=}{\mathbf{n}_R}^2$$
 (12)

where we have additionally assumed that the Fermienergy \mathbf{I}_{f} is larger or at least of the same order as \mathbf{I}_{R} , which is usually the case in experim ental situations. The zeroth-order contribution e=8 is the result obtained by Sinova et al. using directly a zero-frequency perturbative expression for the spin-Hall current neglecting e ects of a nite electron quasi-particle lifetime, (cf. Eq. (8) in Ref. 15). Remarkably, this value is universal in the sense that it is independent of . Therefore, it predicts a nite spin-Hall conductivity even in the lim it of vanishing spinorbit coupling, ! 0, which is certainly an unphysical feature. However, this paradox can be resolved by the observation that the above two lim iting processes do not commute. In fact, in the opposite $\lim_{\mathbb{R}} \mathbb{T}_{\mathbb{R}} = \mathbb{R}$ lowest order of the second term on the rhs. of Eq. (6) cancels the rst one, and the spin-Hall conductivity is given in leading order by

$$S_{xy}^{S,z}(0) = \frac{e}{h} \frac{\|R\|_{f}}{(h-y)^{2}} + 0 \frac{\|R\|_{R}}{h-y}^{2}$$
 (13)

Thus, to obtain the correct dc spin-Hall conductivity, the \R ashba energy " " = m 2 =h should be compared with the energy scale h= of the impurity scattering. If " h= the spin-Hall conductivity is close to its \universal" value e=8 , while it vanishes for small spin-orbit coupling and nite impurity scattering. In epitaxially

grown GaAs quantum wells mobilities = e = m of order $100\text{m}^2\text{=V}$ s can routinely be achieved, corresponding to values for h= of order 0.0lmeV. This is safely smaller than typical values for the Rashba energy reported from experim ents 26 {34}being of order 0.1::1.0meV. How ever, it should be noted that the Rashba coe cient is typically proportional to an external electric eld applied in the growth direction of the quantum well. Therefore also smaller values of the Rashba energy are possible where the nite momentum relaxation time will in uence the value of the spin-Hall conductivity.

IV .HOLES IN THE VALENCE BAND OF III-V SEM ICONDUCTORS

M urakam i, N agaosa, and Zhang have investigated spin-Hall transport in three-dimensional bulk systems of holes in the valence band of III-V sem iconductors 14. These authors used a phenom enological sem iclassical theory to describe adiabatic hole dynamics. Their work was revisited most recently by Culcer et al. 16 within the framework of a sem iclassical theory of wave packet dynamics. Here we will evaluate the spin-Hall conductivity using the rigorous K ubo formula (1). Our starting point 14;16 is Luttinger's four-band Hamiltonian for heavy and light holes in the spherical approximation 35,

$$H = \frac{1}{2m}$$
 $_1 + \frac{5}{2}$ $_2$ p^2 $_2$ $_2$ $_3$ $_3$: (14)

Here m is the bare electron mass, and S are spin-3=2-operators. The dimensionless Luttinger parameter $_1$ and $_2$ describe the valence band of the speci c material with e ects of spin-orbit coupling being included in $_2$. The eigenstates of (14) can be chosen to be eigenstates of the helicity operator = (K S)=k. The heavy holes correspond to = 3=2, while the light holes have = 1=2. From the Kubo formula (1) one nds for the frequency-dependent spin-Hall conductivity after lengthy but elementary calculations

$$\sum_{xy}^{S;z} (!) = \frac{e}{2} \frac{h}{m}^{2} (_{1} + 2_{2})_{2}$$

$$Z_{k_{f}^{h}}^{k_{f}^{1}} dk \frac{k^{4}}{(! + i =)^{2} \frac{2h}{\pi} _{2}k^{2}}; \quad (15)$$

where

$$k_{f}^{h=1} = \frac{r}{\frac{2m}{h^{2}} \cdot r_{f}} \frac{1}{1 + 2 \cdot 2}$$
 (16)

are the Ferm i wave numbers for heavy and light holes, respectively. A gain it is instructive to consider the case for weak spin-orbit coupling, $_2$ $_1$. For $_2$ = 0 we have $k_f^h = k_f^1 = : k_F^0 = 2m "_f = _1h^2$, and therefore the integral in Eq. (15) vanishes for nite 1= > 0 and all

frequencies!. Thus, as before for the case of electrons, the dc spin-Hall conductivity vanishes for vanishing spin-orbit coupling if a nite momentum relaxation rate is taken into account. This result is in contrast to statements in Refs. $^{14;16}$, where such dissipation e ects were neglected. Speci cally, for! = 0 we have

The remaining integral is elementary leading to a rather tedious expression which shall not be given here. However, we see that the value of the above integral is governed by the ratio of he and the \spin-orbit energy" $_{\text{so}} := h^2 _2 (k_f^0)^2 = m = 2 \text{"}_{f=2} = 1$, since k_f^0 is a typical wave number in the integration interval. If he $_{\text{so}}$ the spin-Hall conductivity vanishes as

$$\frac{S_{7Z}}{xy}(0) = \frac{e}{2} 4k_f^0 \quad \frac{\text{"so}}{h=}^2 \quad \frac{2}{1} \\
+ O \quad \frac{\text{"so}}{h=}^4 \quad \frac{\text{"so}}{h=}^2 \quad \frac{2}{1}$$
(18)

where we have also assumed that the ratio $_2$ = $_1$ is small as it is usually the case 36 . In the opposite case h= $_{50}$ one nds

$$\frac{s_{i}z}{xy}(0) = \frac{e}{4^{2}} \frac{1+2_{2}}{2} k_{f}^{h} k_{f}^{l}
+ \frac{k_{f}^{0}}{12} e^{\frac{1}{k_{f}^{h}}} \frac{1}{k_{f}^{h}} \frac{1}{k_{f}^{l}} A \frac{h=}{\mathbf{v}_{so}} e^{\frac{1}{k_{f}^{l}}} + O \frac{h=}{\mathbf{v}_{so}} e^{\frac{1}{k_{f}^{l}}}$$
(19)

W e note that the zeroth order of this result agrees with the expression given in Ref. for the dc spin-Hall conductivity neglecting dissipation e ects , but di ers from the result reported in 14 . On the present stage we cannot comment on the question whether this di erence is an artifact of the semiclassical approache used in Ref. whereas the present result is obtained from a rigorous linear-response theory given by the Kubo formula with full frequency dependence.

Let us illustrate our results on the typical example given in Ref. 14 , where a GaAs sample with hole density n = $10^{19} \, \mathrm{cm}^{-3}$, corresponding to a Fermienergy of order a few ten meV, and a mobility of = e = m = $50 \, \mathrm{cm}^{\, 2} = \mathrm{V} \, \mathrm{s}$. To obtain an upper bound for we take m to be the heavy-hole mass, m $0.5 \, \mathrm{m}$, corresponding to $_1$ 7 and $_2$ 2.5 for GaAs 36 . This leads to a lower estimate for h= being also of order a few ten meV. Thus,

in the above scenario, the nite momentum relaxation time must be taken into account when calculating the spin-Hall conductivity, dierently from the approach in $Ref.^{14}$.

V.CONCLUSIONS

We have studied the spin-Hall transport of electrons and holes in sem iconductors using the Kubo formula in the correct zero-frequency lim it taking into account the nite m om entum relaxation tim e of carriers in real sem iconductors. This approach allows to analyze the range of validity of recent theoretical ndings $^{14\{16}$. In particular, the spin-Hall conductivity is found to vanishe for vanishing spin-orbit coupling if the correct zero-frequency lim it is performed. In the case of conduction band electrons in the presence of Rashba spin-orbit coupling in a highm obility quantum well, spin-orbit interaction dom inates, for typical experimental for the rashba coe cient, the e ects of m om entum relaxation, and the spin-Hall conductivity is close to its \universal" value as predicted in Ref. 15. This situation can be dierent for typical p-doped bulk samples, where dissipation can substantially a ect the spin-Hall transport.

ACKNOW LEDGM ENTS

We thank J. Sinova and A. H. MacDonald for use-ful correspondence. This work was supported by NCCR Nanoscience, the Swiss NSF, DARPA, and ARO.

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de nitions of the spin-current operator.